OMRON



A wide range of contact forms and functions Over 250 different models available

Selection Guide

Ultra small outline package "USOP series" expansion **DIP high-capacity & Low ON resistance series expansion** New DIP small series with High Dielectric Strength available



MOS FET Relays G3VM Series

About MOS FET relays

Omron's Mos Fet Relays lead the industry in Solid State Relay technology, utilizing a LED, PDA and Mos Fet in the load switching current. Our G3VM series of relays offer many benefits including low maintenance costs, small footprint and high-speed switching. As a suitable replacement for a mechanical relay, Mos Fet relays are displacing reed relays as well as relays containing mercury. OMRON has expanded the product lineup by introducing their smallest relay* to date, the new ultra small outline package(USOP) and SSOP which lead the industry in size and performance, with high switching capacity and high sensitivity series available.

*As of September, 2012.

Advantages of MOS FET relays

Ultra small and Weight

Leading the market with substantial space saving offered in our SSOP and new USOP package size

Low driving current

Standard driving current is 2-15mA.

Ultrasensitive type with driving current 1mA(max.) available.

Long operating life

Realize the structure without contacts by sending light signal. Avoid the reduction of life caused by wear of contacts, and realize extended operational life.

Small leakage current

Can withstand external surge current, and not add the snubber circuit. Under normal condition, it is 1 nanometer A or below (GR, LR type), and the leakage current is very small when close.

Excellent shock resistance

All the internal parts use the casting method, and there is not movable part in it, so it has excellent shock resistance and vibration resistance.

High insulation

It turns the voltage into the light, and transfers by the light signal, so it is electrical insulation. It not only can ensure that the Dielectric strength between input and output under normal condition is AC 2500V, but also realizes the serialization of upper 5000V product at the same time, and realize the high insulation.

Silent operation

Avoid the switching voice caused by metal contacts of mechanical relay. Realize the function of silence.

High-speed switching

Comparing with the switching time of 3 \sim 5ms of mechanical relay, its switching time is shortened to 1ms. Realize the quick response performance.

Control the micro analog signal correctly

Comparing with the triac, it reduces the dead zone greatly. The input waveform of micro analog signal dose not distort basically and is converted into output waveform without distortion.



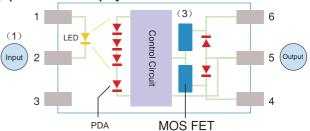
Structure and operational principle of MOS FET relays

[Internal structure] 3MOS FET Epoxy Resin

MOS FET relay consists of the following three components:

- ①LED (light emitting diode)
- ②Photodiode dome array (PDA)
- 3MOS FET

[Operational Principle] (2)



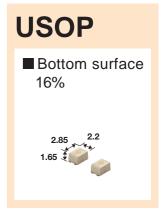
- (1) The LED lights when the current is connected at the input side.
- (2) The light sent by the LED will be converted into voltage again when it is received by the photodiode.
- (3) This voltage will be a gate voltage to drive MOS FET via control circuit.

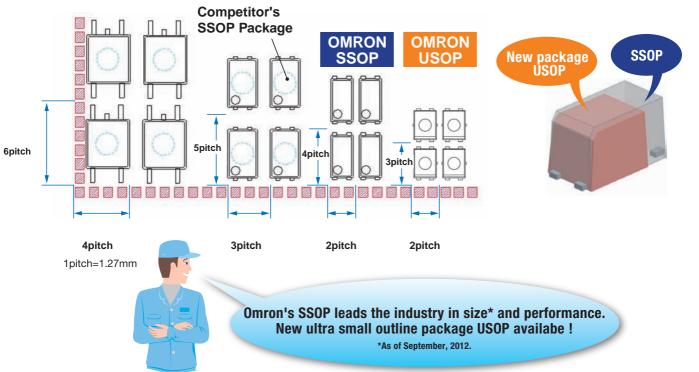
Package of MOS FET Relays

Bottom surface 100%



■Bottom surface 19%





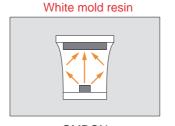
Features of Omron's technology

1. White Mold

High efficient light conductivity

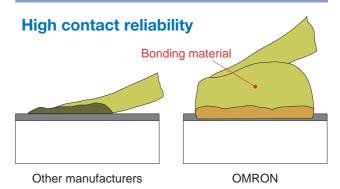
Black mold resin

Other manufacturers



Black mold: only can receive the direct light from LED White mold: can receive the indirect reflecting light from both LED and resin

2. BWB Bonding



OMRON uses more bonding material than that used by other manufacturers; in an effort to improve the contact reliability.

MOS FET Relay Lineup

High Current & Low On-resistance Type

Ideal for power circuit with high current and low on-resistance







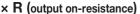


Typical ON Voltage(V) Max. Package Model (mA) Max DIP G3VM-21AR/DR NEW 20 3 0.04 G3VM-21BR/ER NEW 20 4(8) 0.02(0.005)* G3VM-41AR/DR NEW 40 2.5 0.05 G3VM-41BR/ER 40 3.5(7) 0.03(0.008)* G3VM-61AR/DR 60 0.08 G3VM-61BR/ER 60 2.5 0.065 G3VM-61BR1/ER1 NEW 60 3(6)3 0.04(0.01)* G3VM-101AR/DR NEW 100 0.25 G3VM-101BR/ER NEW 2(4) 100 0.1(0.025)* SOP G3VM-21HR 20 2.5(5)* 0.02(0.005)* G3VM-41GR8 40 0.1 G3VM-41HR NEW 40 2.5(5) 0.03(0.008)* G3VM-61GR1 60 0.25 G3VM-61HR NEW 60 2.3(4.6)* 0.04(0.01)* G3VM-81HR 1.25(2.5)* 0.11(0.03)* 80 G3VM-101HR NEW 100 1.4(2.8)* 0.1(0.025)*

*()=C-connection

New Ultra Small Outline Package USOP Type

USOP with low C (capacity between terminals)





Model	Load Voltage(V) Max.	Continuous load current(mA) Max.	Typical ON resistance(Ω)	Capacity between terminals (pF) Typ.
G3VM-21PR10 NEW	20	200	3	8.0
G3VM-21PR11 <i>NEW</i>	20	900	0.18	40
G3VM-41PR12 <i>NEW</i>	40	100	15	0.3
G3VM-41PR10 <i>NEW</i>	40	120	12	0.45
G3VM-41PR11 <i>NEW</i>	40	140	7	0.7
G3VM-51PR NEW	50	300	1	12
G3VM-61PR1 NEW	60	120	10	0.7
G3VM-61PR NEW	60	400	1	20

Small & High Dielectric Strength Type

Dielectric Strength between I/O 5,000Vrms with small DIP4.

Low Power Consumption at 2mA (maximum) driving current*.

*Driving current=Trigger LED forward current

Model	Load Voltage(V) Max.	Continuous load current (mA) Max.	Maximum Trigger LED forward current (mA)	Dielectric strength between input and output (Vrms) Max.
G3VM-41AY/DY NEW	40	2000	2	5000
G3VM-61AY/DY NEW	60	500	2	5000
G3VM-201AY/DY NEW	200	250	2	5000
G3VM-351AY/DY NEW	350	100	2	5000
G3VM-401AY/DY NEW	400	120	2	5000
G3VM-601AY/DY NEW	600	90	2	5000

Ultrasensitive Type

Ideal for power saving with a driving current* 1mA(maximum)

*Driving current=Trigger LED forward current

Model	Load Voltage(V) Max.	Continuous load current (mA) Max.	Maximum Trigger LED forward current (mA)	Operating LED forward current (mA)
G3VM-61G2	60	400	1	2
G3VM-201G1	200	200	1	2
G3VM-351G1	350	100	1	2
G3VM-601G	600	90	1	2

Low Capacity between terminals & Low On-resistance Type (Low C x R)

Ideal for semi-conductor test equipment. Iow C(capacity between terminals)

× R(output on-resistance) type

■ SOP package

Model	Load Voltage(V) Max.	Continuous load current(mA) Max.	Typical ON resistance(Ω)	Capacity between terminals (pF) Typ.
G3VM-21GR	20	160	5	1
G3VM-21GR1	20	300	1	5
G3VM-41GR4	40	250	2	5
G3VM-41GR5	40	300	1	10
G3VM-41GR6	40	120	10	1
G3VM-81GR	80	40	16	2.5
G3VM-81GR1	80	200	5	6.5

SSOP package

Model	Load Voltage(V) Max.	Continuous load current(mA) Max.	Typical ON resistance(Ω)	Capacity between terminals (pF) Typ.
G3VM-21LR	20	160	5	1
G3VM-21LR1	20	450	0.8	5
G3VM-21LR10	20	200	3	0.8
G3VM-41LR4	40	250	2	5
G3VM-41LR5	40	300	1	10
G3VM-41LR6	40	120	10	1
G3VM-41LR10	40	120	12	0.45
G3VM-41LR11	40	140	7	0.7



Product lineup of MOS FET Relays

DIP(Dual Inline Package)											
Load Voltage(V)	Model		Number of	Contact form	Continuous load	Typical ON	Maximum	Maximum	Dielectric strength between input and		
Max.			terminals		current (mA) Max.	resistance(Ω)	turn-ON time (ms)	turn-OFF time (ms)	output (Vrms) Max.		
20	G3VM-21AR/DR	NEW	4	1a	3000	0.04	5.0	1.0	2500		
20	G3VM-21BR/ER	NEW	6	1a	4000	0.02	5.0	1.0	2500		
40	G3VM-41AY/DY	NEW	4	1a	2000	0.09*	5.0	1.0	5000		
40	G3VM-41AR/DR	NEW	4	1a	2500	0.05	5.0	1.0	2500		
40	G3VM-41BR/ER	NEW	6	1a	3500	0.03	5.0	1.0	2500		
60	G3VM-61A1/D1		4	1a	500	1	2.0	0.5	2500		
60	G3VM-61AY/DY	NEW	4	1a	500	0.6	1.0	1.0	5000		
60	G3VM-61AR/DR	NEW	4	1a	2000	0.08	5.0	1.0	2500		
60	G3VM-61B1/E1		6	1a	500	1	2.0	0.5	2500		
60	G3VM-61BR/ER		6	1a	2500	0.065	1.5	0.4	2500		
60	G3VM-61BR1/ER1	NEW	6	1a	3000	0.04	5.0	1.0	2500		
60	G3VM-62C1/F1		8	2a	500	1	2.0	0.5	2500		
100	G3VM-101AR/DR	NEW	4	1a	1000	0.25	5.0	1.0	2500		
100	G3VM-101BR/ER	NEW	6	1a	2000	0.1	5.0	1.0	2500		
200	G3VM-201AY/DY	NEW	4	1a	250	5	1.0	1.0	5000		
350	G3VM-351AY/DY	NEW	4	1a	100	35*	1.0	1.0	5000		
350	G3VM-2L/2FL		4	1a	120	22	1.0	1.0	2500		
350	G3VM-351A/D		4	1a	120	35*	1.0	1.0	2500		
350	G3VM-351B/E		6	1a	120	35	1.0	1.0	2500		
350	G3VM-352C/F		8	2a	120	35*	1.0	1.0	2500		
350	G3VM-WL/WFL		8	2a	120	22	1.0	1.0	2500		
350	G3VM-353A/D		4	1b	150	15	1.0	3.0	2500		
350	G3VM-353B/E		6	1b	150	15	1.0	3.0	2500		
350	G3VM-354C/F		8	2b	150	15	1.0	1.0	2500		
350	G3VM-355CR/FR		8	1a1b	120	15	1.0	3.0	2500		
400	G3VM-401A/D		4	1a	120	18	1.0	1.0	2500		
400	G3VM-401AY/DY	NEW	4	1a	120	22*	1.0	1.0	5000		
400	G3VM-401B/E		6	1a	120	17	1.0	1.0	2500		
400	G3VM-401BY/EY		6	1a	120	17	1.0	1.0	5000		
400	G3VM-402C/F		8	2a	120	18	1.0	1.0	2500		
600	G3VM-601AY/DY	NEW	4	1a	90	45*	1.0	1.0	5000		
600	G3VM-601BY/EY		6	1a	100	30	1.5	1.0	5000		

On-resistance when saturated

SOP(Small Outline Package)											
Load Voltage(V) Max.	Model		Number of terminals	Contact form	Continuous load current (mA) Max.	Typical ON resistance(Ω)	Maximum turn-ON time (ms)	Maximum turn-OFF time (ms)	Dielectric strength between input and output (Vrms) Max.		
20	G3VM-21GR		4	1a	160	5	0.5	0.5	1500		
20	G3VM-21GR1		4	1a	300	1	0.5	0.5	1500		
20	G3VM-21HR		6	1a	2500	0.02	5.0	1.0	1500		
40	G3VM-41GR4		4	1a	250	2	0.5	0.5	1500		
40	G3VM-41GR5		4	1a	300	1	0.5	0.5	1500		
40	G3VM-41GR6		4	1a	120	10	0.5	0.5	1500		
40	G3VM-41GR8		4	1a	1000	0.1	3.0	0.5	1500		
40	G3VM-41HR	NEW	6	1a	2500	0.03	5.0	1.0	1500		
60	G3VM-61VY	NEW	4	1a	70	25	5.0	5.0	3750		
60	G3VM-61G1		4	1a	400	1	2.0	0.5	1500		
60	G3VM-61G2		4	1a	400	1	8.0	3.0	1500		
60	G3VM-61GR1		4	1a	1000	0.25	3.0	1.0	1500		
60	G3VM-61H1		6	1a	400	1	2.0	0.5	1500		
60	G3VM-61HR	NEW	6	1a	2300	0.04	5.0	1.0	1500		
60	G3VM-62J1		8	2a	400	1	2.0	0.5	1500		
80	G3VM-81G1		4	1a	350	1	0.5	0.5	1500		
80	G3VM-81GR		4	1a	40	16	0.5	0.5	1500		
80	G3VM-81GR1		4	1a	200	5	0.5	0.5	1500		
80	G3VM-81HR		6	1a	1250	0.11	3.0	1.0	1500		
100	G3VM-101HR	NEW	6	1a	1400	0.1	5.0	1.0	1500		
200	G3VM-201G		4	1a	50	40	0.5	0.2	1500		
200	G3VM-201G1		4	1a	200	5	8.0	3.0	1500		
200	G3VM-S5		4	1a	200	5	1.5	1.0	1500		
200	G3VM-201H1		6	1a	200	5	1.5	1.0	1500		

On-resistance when saturated

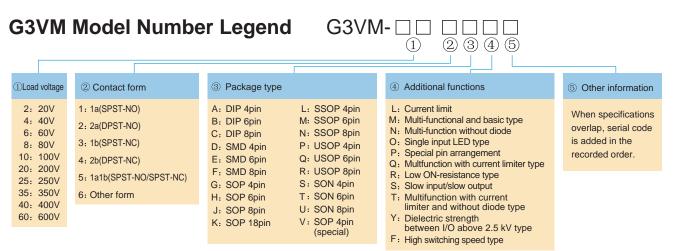
Product lineup of MOS FET Relays

	SOP(Small Outline Package)											
Load Voltage(V) Max.	Model	Number of terminals	Contact form	Continuous load current (mA) Max.	Typical ON resistance(Ω)	Maximum turn-ON time (ms)	Maximum turn-OFF time (ms)	Dielectric strength between input and output (Vrms) Max.				
200	G3VM-202J1	8	2a	200	5	1.5	1.0	1500				
350	G3VM-351G	4	1a	110	35 [*]	1.0	1.0	1500				
350	G3VM-351G1	4	1a	100	35	5.0	3.0	1500				
350	G3VM-351GL	4	1a	120	15	1.0	1.0	1500				
350	G3VM-351H	6	1a	110	35*	1.0	1.0	1500				
350	G3VM-352J	8	2a	110	35 [*]	1.0	1.0	1500				
350	G3VM-353G	4	1b	120	15	1.0	3.0	1500				
350	G3VM-353H	6	1b	120	15	1.0	3.0	1500				
350	G3VM-354J	8	2b	120	15	1.0	3.0	1500				
350	G3VM-355JR	8	1a1b	120	15	1.0	3.0	1500				
400	G3VM-401G	4	1a	120	17	1.0	1.0	1500				
400	G3VM-401H	6	1a	120	17	1.0	1.0	1500				
400	G3VM-402J	8	2a	120	17	1.0	1.0	1500				
600	G3VM-601G	4	1a	90	45	8.0	3.0	1500				

ON registance when it is saturation

	SSOP(Shrink Small Outline Package)												
Load Voltage(V) Max.	Model	Number of terminals	Contact form	Continuous load current (mA) Max.	Typical ON resistance(Ω)	Maximum turn-ON time (ms)	Maximum turn-OFF time (ms)	Dielectric strength between input and output (Vrms) Max.					
20	G3VM-21LR	4	1a	160	5	0.5	0.5	1500					
20	G3VM-21LR1	4	1a	450	0.8	0.5	0.5	1500					
20	G3VM-21LR10	4	1a	200	3	0.2	0.2	1500					
20	G3VM-21LR11	4	1a	900	0.18	2.0	1.0	1500					
40	G3VM-41LR4	4	1a	250	2	0.5	0.5	1500					
40	G3VM-41LR5	4	1a	300	1	0.5	0.5	1500					
40	G3VM-41LR6	4	1a	120	10	0.5	0.5	1500					
40	G3VM-41LR10	4	1a	120	12	0.2	0.3	1500					
40	G3VM-41LR11	4	1a	140	7	0.2	0.2	1500					
60	G3VM-61LR	4	1a	400	1	1.0	1.0	1500					
80	G3VM-81LR	4	1a	120	7.5	0.25	0.2	1500					
100	G3VM-101LR	4	1a	80	8	0.3	0.3	1500					

	USOP(Ultra Small Outline Package)												
Load Voltage(V) Max.	Model		Number of terminals	Contact form	Continuous load current (mA) Max.	Typical ON resistance(Ω)	Maximum turn-ON time (ms)	Maximum turn-OFF time (ms)	Dielectric strength between input and output (Vrms) Max.				
20	G3VM-21PR10	NEW	4	1a	200	3	0.2	0.2	500				
20	G3VM-21PR11	NEW	4	1a	900	0.18	2.0	1.0	500				
40	G3VM-41PR12	NEW	4	1a	100	15	0.2	0.2	500				
40	G3VM-41PR10	NEW	4	1a	120	12	0.2	0.3	500				
40	G3VM-41PR11	NEW	4	1a	140	7	0.2	0.2	500				
50	G3VM-51PR	NEW	4	1a	300	1	0.5	0.4	500				
60	G3VM-61PR1	NEW	4	1a	120	10	0.2	0.2	500				
60	G3VM-61PR	NEW	4	1a	400	1	0.5	0.5	500				



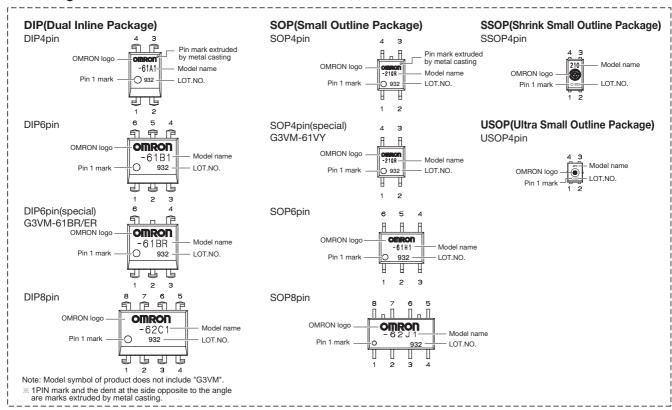
Note 1: Some products may have a different model number structure.

Note 2: In order to avoid the confusion of I (English letter) and 1 (number), I (English letter) are not used here.

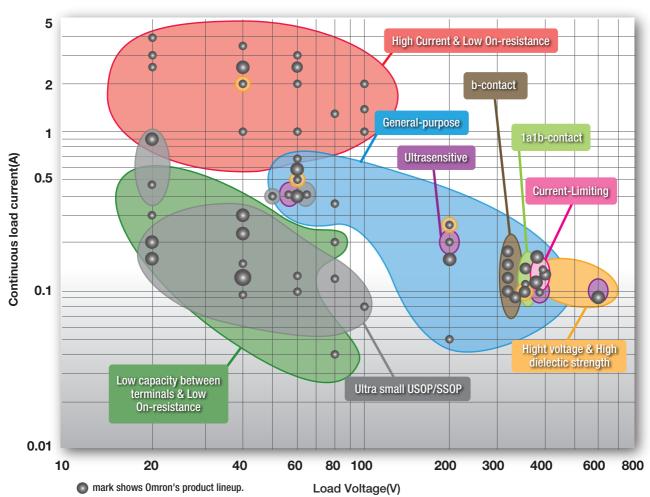
Note 3: For 4-pin SOP models, where the available marking space is insufficient to clearly differentiate model numbers with 6 or more suffix digits, the package type code ③ is omitted.

Product lineup of MOS FET Relays

Package



Product Map by features



Target Applications

Communication Equipment Modem FAX Network equipment PBX •Transmission equipment General -purpose/ b-contact type G3VM-61A1/D1 G3VM-351A/D G3VM-353A/D

Test and Measurement Equipment

- ATE(Automated test equipment)
- Oscilloscope
- Probe/Load card
- IC tester



Ultra-small/Low CXR type

G3VM-21GRxx/41GRxx/81GRXX G3VM-21LRxx/41LRxx/

61LR/81LR/101LR

G3VM-21PRxx/41PRxx/61PRxx





Security Equipment

- Smoke and gas detection equipment
- Household safety panel
- Human detection sensor
- Video intercom



Silent/Ultrasensitive type

G3VM-61G1/G2/VY G3VM-351G/351G1

Electric Meter

- Electric Meter
- Smart Meter
- Gas Meter



High Dielectric Strength type

G3VM-351AY/DY

G3VM-401AY/DY

G3VM-401BY/EY G3VM-601AY/DY

G3VM-601BY/DY

There are many other usages beyond the above applications.

Medical Equipment

Broadcasting Equipment

Factory Automation Equipment

FA/Amusement Equipment

For more detailed information, please contact your local Omron Representative.

Note: Do not use this document to operate the Unit.

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Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

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